NSN 5962-00-216-4144

Memory Microcircuit - Page 1 of 1



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Body Outside Diameter:

Between 0.335 inches and 0.370 inches

Body Height:

Between 0.165 inches and 0.185 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and negative outputs and positive outputs and w/field effect transistor switch and internally compensated

Inclosure Material:

Glass and metal

Inclosure Configuration:

Can

Input Circuit Pattern:

2 input

Case Outline Source And Designator:

T0-99 joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

15.0 volts power source

Time Rating Per Chacteristic:

300.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Terminal Type And Quantity:

8 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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